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Dual J-K Flip-Flops (with Preset and Clear)



ADE-205-435 (Z) 1st. Edition Sep. 2000

#### **Description**

Each flip-flop has independent J, K, preset, clear and clock inputs and Q and  $\overline{Q}$  outputs. This device is edge sensitive to the clock input and change state on the negative going transition of the clock pulse. Clear and preset are independent of the clock and accomplished by a low logic level on the corresponding input.

#### **Features**

• High Speed Operation:  $t_{pd}$  (Clock to Q) = 17 ns typ ( $C_L = 50 \text{ pF}$ )

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage:  $V_{CC} = 2 \text{ to } 6 \text{ V}$ 

• Low Input Current: 1 μA max

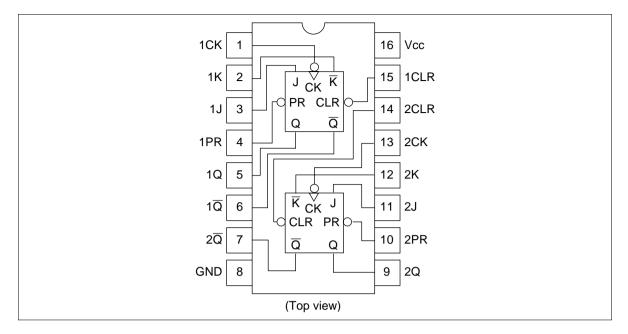
• Low Quiescent Supply Current:  $I_{CC}$  (static) = 2  $\mu$ A max (Ta = 25°C)

#### **Function Table**

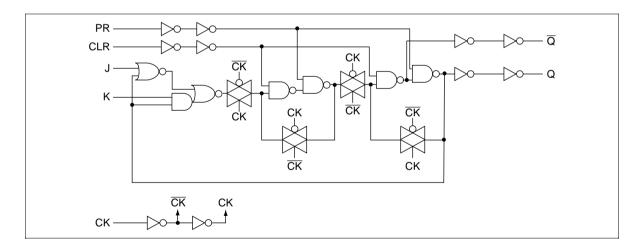
Inputs					Output	
Preset	Clear	Clock	J	K	Q	Q
L	Н	Χ	Χ	X	Н	L
Н	L	Χ	Χ	X	L	Н
L	L	Χ	Χ	Χ	H* <sup>1</sup>	H* <sup>1</sup>
Н	Н	_	L	L	No Change	е
Н	Н		L	Н	L	Н
Н	Н	_	Н	L	Н	L
Н	Н	_	Н	Н	Toggle	
Н	Н	L	Х	Х	No Change	e
Н	Н	Н	Х	Х	No Change	e
Н	Н		Χ	Χ	No Change	e

Note: 1. Q and  $\overline{Q}$  will remain HIGH as long as Preset and Clear are Low, but Q and  $\overline{Q}$  are unpredictable, if Preset and Clear go HIGH simultaneously.

## **Pin Arrangement**



## Logic Diagram (1/2)



# **DC** Characteristics

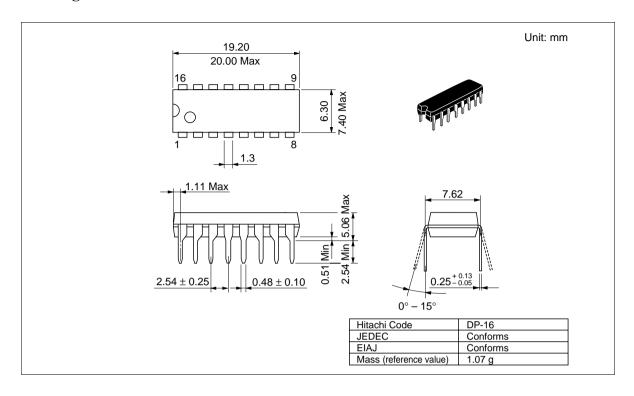
			Ta =	= 25°(	3	Ta = - +85°C	–40 to	_		
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions	
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	<u> </u>	_	3.15	_	_		
		6.0	4.2	_	_	4.2		_		
	V <sub>IL</sub>	2.0	_	_	0.5	_	0.5	V		
		4.5	_	_	1.35	_	1.35	_		
		6.0	_	_	1.8	_	1.8	=		
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0	_	1.9	_	V	Vin = $V_{IH}$ or $V_{IL}$ $I_{OH}$ = $-20 \mu$	A
		4.5	4.4	4.5		4.4	_	_		
		6.0	5.9	6.0	_	5.9	_	=		
		4.5	4.18	s —	_	4.13	_	=	$I_{OH} = -4 \text{ m/s}$	4
		6.0	5.68	3 —	_	5.63	_	=	$I_{OH} = -5.2 \text{ r}$	nA
	V <sub>OL</sub>	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL} I_{OL} = 20 \mu A$	
		4.5	_	0.0	0.1	_	0.1	=		
		6.0	_	0.0	0.1	_	0.1	=		
		4.5	_	_	0.26	_	0.33	=	$I_{OL} = 4 \text{ mA}$	
		6.0	_	_	0.26	_	0.33	=	$I_{OL} = 5.2 \text{ m}.$	A
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GND	
Quiescent supply current	I <sub>cc</sub>	6.0	_	_	2.0	_	20	μΑ	$Vin = V_{CC}$ or GND, lout = 0	μΑ

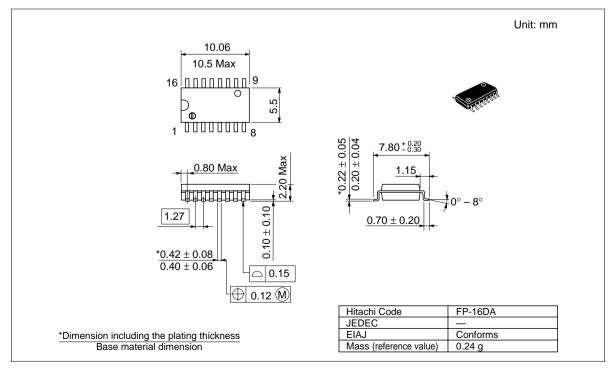
**AC Characteristics** ( $C_L = 50 \text{ pF}$ , Input  $t_r = t_f = 6 \text{ ns}$ )

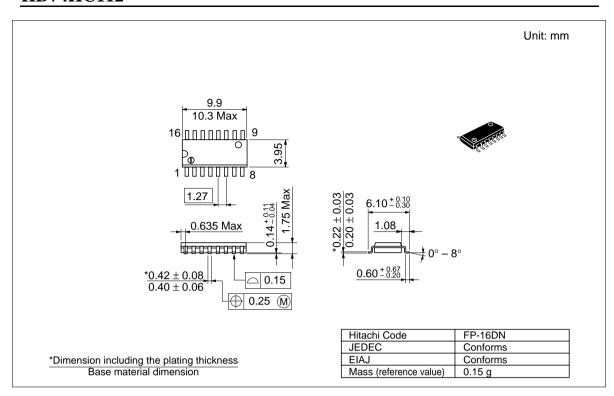
	Ta = -40  to
Ta = 25°C	+85°C

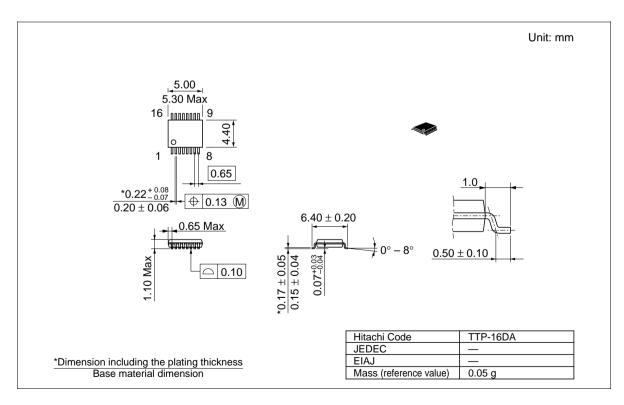
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Maximum clock	f <sub>max</sub>	2.0	_	_	6	_	5	MHz	
frequency		4.5	_	_	30	_	24	_	
		6.0	_	_	35	_	28	_	
Propagation delay	t <sub>PLH</sub>	2.0	_	_	150	_	190	ns	Clock to Q or Q
time	$t_{\tiny PHL}$	4.5	_	17	30	_	38	_	
		6.0	_	_	26	_	33	_	
		2.0	_	_	140	_	175	_	Clear to Q or Q
		4.5	_	15	28	_	35		
		6.0	_	_	24	_	30	_	
		2.0	_	_	140	_	175	_	Preset Q or Q
		4.5	_	16	28	_	35	_	
		6.0	_	_	24	_	30	_	
Pulse width	t <sub>w</sub>	2.0	80	_	_	100	_	ns	Clock, Clear
		4.5	16	9	_	20	_	_	
		6.0	14	_	_	17	_	_	
Setup time	t <sub>su</sub>	2.0	100	_	_	125	_	ns	Data to Clock
		4.5	20	3	_	25	_		
		6.0	17	_	_	21	_		
Hold time	t <sub>h</sub>	2.0	5	_	_	5	_	ns	Clock to Data
		4.5	5	-2	_	5	_	_	
		6.0	5	_	_	5	_		
Removal time	t <sub>rem</sub>	2.0	100	_	_	125	_	ns	Clear to Clock
		4.5	20	2	_	25	_		
		6.0	17	_	_	21	_	_	
Output rise/fall	t <sub>TLH</sub>	2.0	_	_	75	_	95	ns	
time	$t_{\scriptscriptstyle THL}$	4.5	_	5	15	_	19	_	
		6.0	_	_	13	_	16		
Input capacitance	Cin	_	_	5	10	_	10	pF	

#### **Package Dimensions**









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# IITACHI

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

**URL** NorthAmerica http://semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg Europe Asia http://sicapac.hitachi-asia.com Japan http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Germany

Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Fax: <1>(408) 433-0223 Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00

> Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <886>-(2)-2718-3666 Tel: <44> (1628) 585000 Fax: <44> (1628) 585160

Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00, Singapore 049318 Tel: <65>-538-6533/538-8577 Fax: <65>-538-6933/538-3877 URL: http://www.hitachi.com.sg

Hitachi Asia Ltd. (Taipei Branch Office) 4/F, No. 167, Tun Hwa North Road, Hung-Kuo Building, Taipei (105), Taiwan

Fax: <886>-(2)-2718-8180 Telex: 23222 HAS-TP URL: http://www.hitachi.com.tw Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon, Hong Kong

Tel: <852>-(2)-735-9218 Fax: <852>-(2)-730-0281 URL: http://www.hitachi.com.hk

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